

Notice of References Cited	Application/Control No. 10/074,564	Applicant(s)/Patent Under Reexamination TODD ET AL.	
	Examiner Brook Kebede	Art Unit 2823	Page 1 of 1

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	C	US-6,161,498	12-2000	Toraguchi et al.	118/723MW
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NON-PATENT DOCUMENTS

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*A copy of this reference is not being furnished with this Office action. (See MPEP § 707.05(a).)
Dates in MM-YYYY format are publication dates. Classifications may be US or foreign.